



DMT6002LPS

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max Tc = +25°C (Note 9) |
|-------------------|-----------------------------|--|
| 60V | 2mΩ @ V _{GS} = 10V | 100A |
| | $3m\Omega @ V_{GS} = 6V$ | 100A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Switching

Notes:

- Synchronous Rectification
- DC-DC Converters

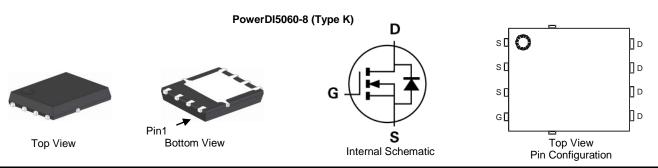
60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8 (Type K)

Features

- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: PowerDI[®]5060-8 (Type K)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (@3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|------------------------|---------------------|
| DMT6002LPS-13 | PowerDI5060-8 (Type K) | 2,500 / Tape & Reel |

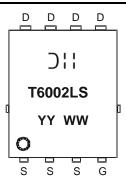
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website athttps://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



] | =Manufacturer's Marking
T6002LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 18 = 2018)
WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|---|------------------------|------------------|------|----|
| Drain-Source Voltage | | V _{DSS} | 60 | V |
| Gate-Source Voltage | | V _{GSS} | ±20 | V |
| | T _C = +25°C | | 100 | ٨ |
| Continuous Drain Current, $V_{GS} = 10V$ (Notes 6 & 9) | T _C = +70°C | ID | 100 | A |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | I _{DM} | 400 | А |
| Continuous Body Diode Forward Current (Note 6) | T _C = +25°C | I _S | 100 | А |
| Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%) | | I _{SM} | 400 | А |
| Avalanche Current, L = 3mH | | I _{AS} | 14 | А |
| Avalanche Energy, L = 3mH | | E _{AS} | 294 | mJ |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 2.3 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 55 | °C/W |
| Total Power Dissipation (Note 6) | PD | 167 | W |
| Thermal Resistance, Junction to Case (Note 6) | R _{θJC} | 0.9 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-------|------|-------|---|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 60 | — | _ | V | $V_{GS} = 0V, I_D = 250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | — | 1 | μA | $V_{DS} = 48V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | _ | — | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | _ | 3 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | | — | 1.5 | 2 | mΩ | $V_{GS} = 10V, I_D = 50A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 2.2 | 3 | 11122 | $V_{GS} = 6V, I_D = 50A$ | |
| Diode Forward Voltage | V _{SD} | _ | — | 1.2 | V | $V_{GS} = 0V, I_{S} = 50A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | | 6555 | — | | $V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz | |
| Output Capacitance | C _{oss} | | 2264 | — | pF | | |
| Reverse Transfer Capacitance | C _{rss} | — | 187 | _ | | | |
| Gate Resistance | Rg | — | 0.7 | - | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 10V) | Qg | — | 130.8 | — | | | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 63.6 | - | nC | | |
| Gate-Source Charge | Q _{gs} | _ | 20.8 | — | nc | $V_{DS} = 30V, I_D = 50A$ | |
| Gate-Drain Charge | Q _{gd} | _ | 29.4 | _ | | | |
| Turn-On Delay Time | t _{D(ON)} | _ | 11.2 | — | | | |
| Turn-On Rise Time | t _R | _ | 10.8 | — | | $V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 50A, R_g = 2.5\Omega$ | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 44 | — | ns | | |
| Turn-Off Fall Time | t _F | _ | 19.5 | — | | | |
| Reverse Recovery Time | t _{RR} | _ | 61.8 | — | ns | | |
| Reverse Recovery Charge | Q _{RR} | — | 123 | — | nC | I _F = 50A, di/dt = 100A/μs | |

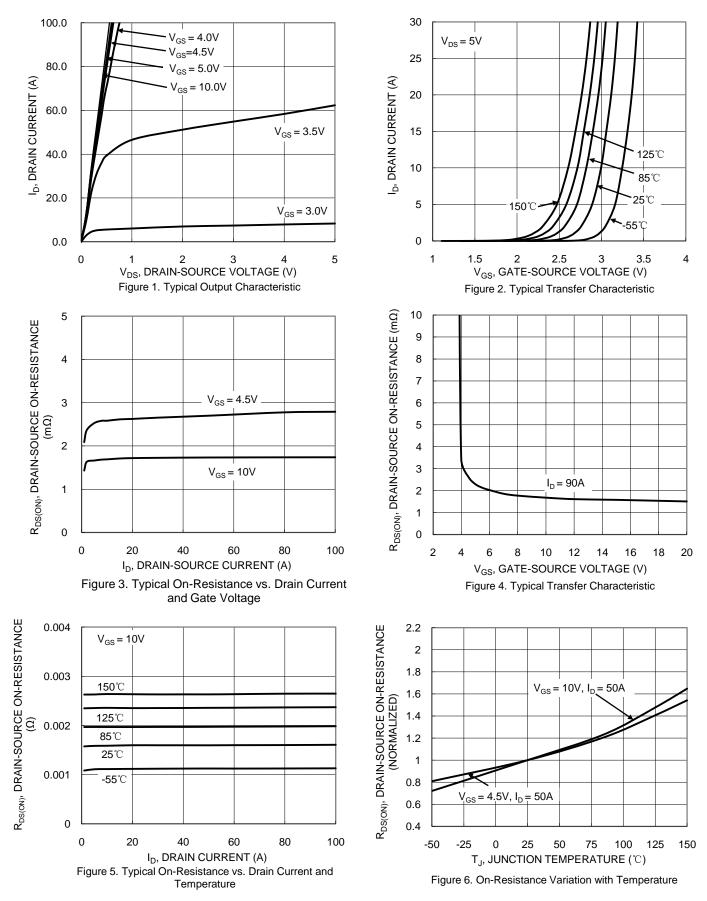
5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

6. Thermal resistance from junction to soldering point (on the exposed drain pad).
7. Short duration pulse test used to minimize self-heating effect.

Guaranteed by design. Not subject to product testing.
 Package limited.



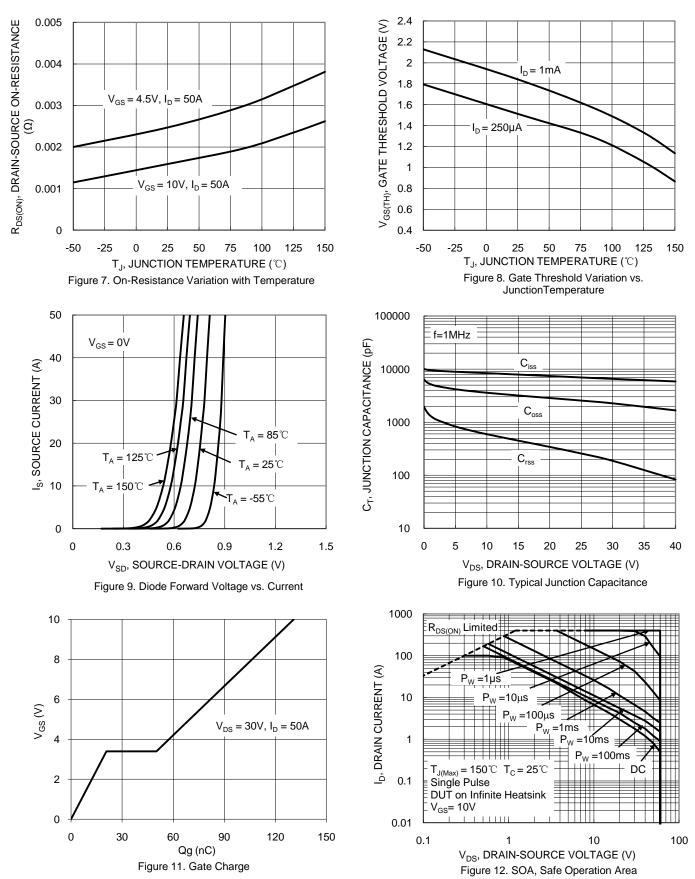
DMT6002LPS



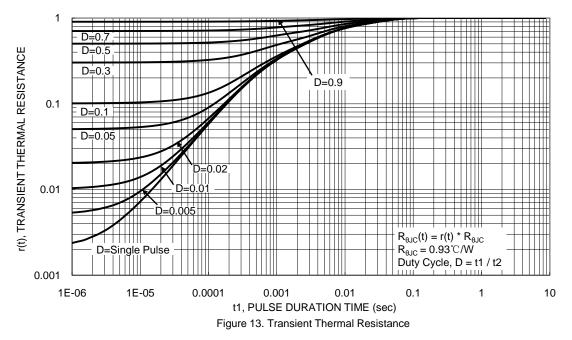
DMT6002LPS Document number: DS39090 Rev. 2 - 2



DMT6002LPS



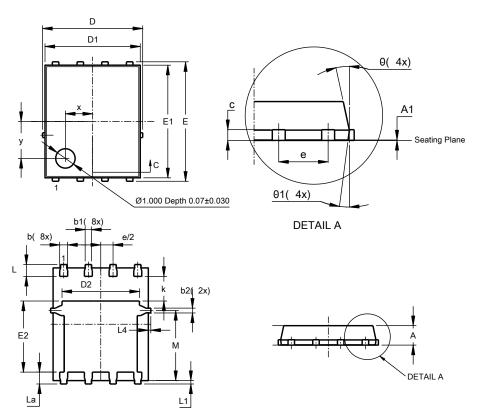






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



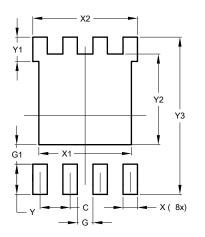
| PowerDI5060-8 (Type K) | | | | |
|---------------------------|---------|---------|-------|--|
| Dim | Min | Max | Тур | |
| Α | 0.90 | 1.10 | 1.00 | |
| A1 | 0 | 0.05 | 0.02 | |
| b | 0.33 | 0.51 | 0.41 | |
| b1 | 0.300 | 0.366 | 0.333 | |
| b2 | 0.20 | 0.35 | 0.25 | |
| С | 0.23 | 0.33 | 0.277 | |
| D | 5 | .15 BS0 | 2 | |
| D1 | 4.85 | 4.95 | 4.90 | |
| D2 | - | - | 3.98 | |
| Е | 6 | .15 BS0 | 2 | |
| E1 | 5.75 | 5.85 | 5.80 | |
| E2 | 3.56 | 3.725 | 3.66 | |
| е | 1 | .27BSC |) | |
| k | - | - | 1.27 | |
| L | 0.51 | 0.71 | 0.61 | |
| La | 0.51 | 0.675 | 0.61 | |
| L1 | 0.05 | 0.20 | 0.175 | |
| L4 | - | - | 0.125 | |
| М | 3.50 | 3.71 | 3.605 | |
| х | - | - | 1.400 | |
| У | - | - | 1.900 | |
| θ | 10° | 12° | 11° | |
| θ1 | 6° | 8° | 7° | |
| All | Dimensi | ions in | mm | |

PowerDI5060-8 (Type K)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type K)



| Dimensions | Value | | |
|------------|---------|--|--|
| Dimensions | (in mm) | | |
| С | 1.270 | | |
| G | 0.660 | | |
| G1 | 0.820 | | |
| Х | 0.610 | | |
| X1 | 3.910 | | |
| X2 | 4.420 | | |
| Y | 1.270 | | |
| Y1 | 1.020 | | |
| Y2 | 3.810 | | |
| Y3 | 6.610 | | |



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